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# Design and Production of the LHCb Silicon Tracker

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### LHCb Silicon Tracker



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### Inner Tracker



#### Three stations with four layers each:

- 1-sensor ladders above/below beam pipe
- 2-sensor ladders left/right of beam pipe



~ 4.2 m², 504 silicon sensors, 336 modules, 130k readout strips

#### Main concerns in design phase:

- material budget
  - sensors as thin as possible
    320 µm for 1-sensor ladders
    410 µm for 2-sensor ladders
  - supports / cooling etc.
- cost (number of r/o channels)
  - large pitch (197 µm)

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# Trigger Tracker



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## Silicon Tracker Readout

### "Beetle" front-end readout chip:

- radiation-hard design in 0.25  $\mu$ m CMOS
- analog pipeline, multiplexed analog readout
- adjustable shaping time of ~ 25 ns

### Digital optical readout link:





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### Detector R&D

#### Main concerns:

- required sensor thickness for Inner Tracker
- S/N for long r/o strips of Trigger Tracker (37 cm long strips read out at 25 ns !)
- signal integrity for readout sectors with Kapton interconnect

#### Various prototypes tested:

- different sensor thicknesses, strip lengths, strip geometries (pitch, implant width)
- with and without Kapton interconnects
- all read out with Beetle front-end chip
- test beams and IR-laser test stand







# Main Findings from R&D

#### Noise proportional to detector capacitance:

- observed no significant noise contribution from strip resistance (up to 33 cm strip length)
- confirmed by SPICE simulation of r/o strips (as LCR network) and Beetle front-end amplifier
- careful: convolution of detector noise spectrum with frequency response function of amplifier

-> do not use simple recipesto estimate this noise contribution

- Also: <u>no deterioration of signal integrity</u> <u>due to the Kapton interconnects</u>
- behave just as an additional capacitive load
- again, confirmed in the SPICE simulation





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# Main Findings from R&D

#### <u>Significant loss of CCE in between readout strips</u>:

- observed on all tested detectors
- not an artefact from clustering
- size of charge loss is independent of strip length, overbiasing, shaping time
- but seems to depend roughly linearly on the ratio (pitch-width) / thickness
- attributed to charge trapping at silicon bulk – oxide interface in between the strip implants
- unfortunately never found the time to do a proper simulation ...

sensor thicknesses chosen such that S/N > 12 in between strips



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## **IT Module Production**

### Main production steps:

- position hybrid & pitch adaptor, glue them onto the sandwich support
- r/o functionality test
- position and glue silicon sensor(s)
- measure sensor alignment
- bond hybrid and pitch adaptor,
   bond bias and GND to the sensor(s)
- r/o functionality and HV test
- bond all readout strips
- 48h burn-in test:
  - 34 temperature cycles between +40°C and  $-5^{\circ}C$
  - detectors continuously biased at 500 V
  - readout tests at different temperatures







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# **Trigger Tracker Production**

#### <u>"Stage I" production steps</u>:

- place seven sensors and lower hybrid (use sensor edges for positioning)
- measure and correct alignment (CMM)
- glue support rails along the edges
- measure final sensor alignment
- glue bias voltage cable along back of module, connect GND and bias voltage (soldering / bonding)
- bond sensors and pitch adaptor
- 36 h burn-in test:
  - several temperature cycles between 25°C and 5°C
  - detectors biased at 500 V, currents monitored
  - IV curves and readout tests at different temperatures







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# **Trigger Tracker Production**

#### <u>"Stage II" production steps</u>:

- glue Kevlar protection caps over bonds
- assemble, bond and mount Kapton interconnect cable and upper hybrid onto the detector module
- solder GND connections to lower hybrid
- 36h burn-in test

#### "Stage III" production steps:

- for "4-2-1" modules repeat stage-II steps for the 3<sup>rd</sup> readout sector
- 36h burn-in test











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### **Burn-In Tests**

#### Thermal cycling with readout tests at different temperatures

- pedestal and noise measurements
- pulse-shape and charge-collection scans
  - IR laser to inject signals in sensors (TT)
  - internal test pulse on Beetle chip (TT and IT)
- identify bad strips (open, short, pinhole) from analysis of noise and test-pulse data







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### **Burn-In Tests**

#### Thermal cycling with readout tests at different temperatures

- pedestal and noise measurements
- pulse-shape and charge-collection scans
  - IR laser to inject signals in sensors (TT)
  - internal test pulse on Beetle chip (TT and IT)
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## Module Quality

number of r/o sectors

#### TT module production finished

- 147 modules produced (= 15% spares)
- three modules "lost" during production
- three modules had to go through "major" repair cycle (e.g. replace sensor)
- found 109 bad strips out of ~ 158 k tested
- leakage currents typically < 500 nA per sensor</li>

#### IT production ongoing, expect to finish in March

- currently ~ 300 modules produced and fully tested
- some 15 of these show unstable HV behaviour between 350 V and 500 V, under investigation
- fraction of bad strips « 1 %
- leakage currents typically < 400 nA per sensor</li>





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## Module Quality

#### <u>Positioning precision</u> (benchmark: expected spatial resolution of ~ 50 µm)

- excellent relative positioning of the sensors on a module
- each module can be treated as one unit in software alignment, no need to align individual sensors
- positioning of sensors on supports worse than what we had hoped for (for IT, not measured for TT)
- mainly due to worse than expected tolerances on production templates
- no problem: software alignment of individual modules was always foreseen





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### Silver Glue

Silver glue on aluminium is a bad idea (similar effects reported by CMS)

- TT: use Kapton cable to connect bias voltage to sensor backplane
- electrical connection initially done with silver glue
  - TT9-75: Elecolit 340 (one-component "silver paint")
  - TT76-155: Elecolit 325 (two-component epoxy)
- measured resistance of all connections
  - shortly after module production
  - again after a few weeks / months
- find significant increase of resistance
  - for both types of silver glue
  - typically a few hundred Ohms now
- added bond connections on all sensors to avoid long-term problems
- also: some GND connections on IT done with silver glue -> add bond wires

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# Installation / Commissioning

- TT (one large detector box):
- test assembly of detector box in the lab
  - included one half-layer of modules
  - extensive mechanical and thermal tests
- detector box now installed in the experiment
- modules will be installed layer by layer
  - HV / readout tests in between any two layers
  - first modules foreseen for March
- IT (12 individual detector boxes):
- first box assembled and being debugged
- commissioning of each box in the lab
  - installation of first box foreseen for March

<u>Readout electronics</u> (24+24 "Service Boxes"):

- assembly and burn-in tests underway
- valuable experience from module burn-in stands

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#### <u>Production of detector modules approaching completion</u>

- "115%" of TT modules and ~90% of IT modules produced and tested
- number of "lost" modules so far quite small

Quality of modules very satisfactory

- number of bad channels low (< 0.1%)</li>
- leakage currents small (< 500 nA / sensor at 500 V)</li>
- sensor-sensor alignment good (rms < 10 µm)
- noise / pulse shape distributions as expected

What to do different / better next time ?

- build "final" modules much earlier on
- reserve more time for transition from prototyping to series production